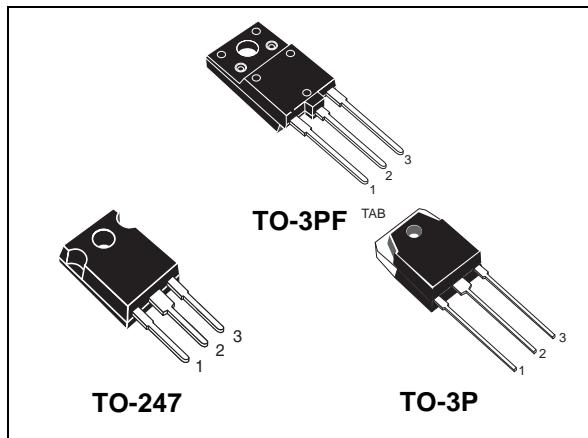


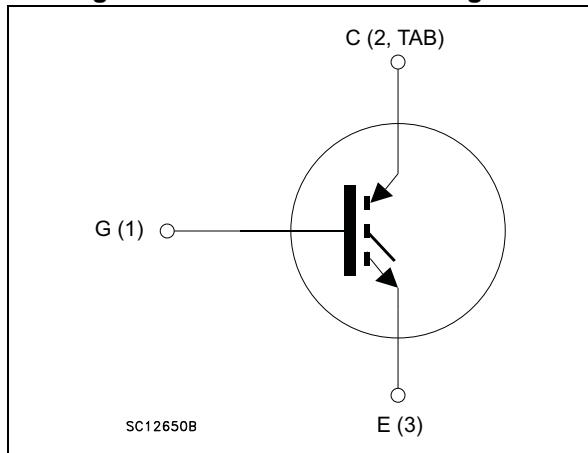
# STGW40H65FB, STGFW40H65FB, STGWT40H65FB

Trench gate field-stop IGBT, HB series  
650 V, 40 A high speed

Datasheet - production data



**Figure 1. Internal schematic diagram**



## Features

- Maximum junction temperature:  $T_J = 175 \text{ }^{\circ}\text{C}$
- High speed switching series
- Minimized tail current
- Very low saturation voltage:  $V_{CE(\text{sat})} = 1.6 \text{ V}$  (typ.) @  $I_C = 40 \text{ A}$
- Tight parameters distribution
- Safe paralleling
- Low thermal resistance
- Lead free package

## Applications

- Photovoltaic inverters
- High frequency converters

## Description

This device is an IGBT developed using an advanced proprietary trench gate and field-stop structure. The device is part of the new HB series of IGBTs, which represent an optimum compromise between conduction and switching losses to maximize the efficiency of any frequency converter. Furthermore, a slightly positive  $V_{CE(\text{sat})}$  temperature coefficient and very tight parameter distribution result in safer paralleling operation.

**Table 1. Device summary**

Order code	Marking	Package	Packaging
STGW40H65FB	GW40H65FB	TO-247	Tube
STGFW40H65FB	GFW40H65FB	TO-3PF	Tube
STGWT40H65FB	GWT40H65FB	TO-3P	Tube

## Contents

<b>1</b>	<b>Electrical ratings</b>	<b>3</b>
<b>2</b>	<b>Electrical characteristics</b>	<b>4</b>
2.1	Electrical characteristics (curves)	6
<b>3</b>	<b>Test circuits</b>	<b>10</b>
<b>4</b>	<b>Package mechanical data</b>	<b>11</b>
<b>5</b>	<b>Revision history</b>	<b>15</b>

# 1 Electrical ratings

**Table 2. Absolute maximum ratings**

Symbol	Parameter	Value		Unit
		TO-247, TO-3P	TO-3PF	
$V_{CES}$	Collector-emitter voltage ( $V_{GE} = 0$ )	650		V
$I_C$	Continuous collector current at $T_C = 25^\circ\text{C}$	80		A
$I_C$	Continuous collector current at $T_C = 100^\circ\text{C}$	40		A
$I_{CP}^{(1)}$	Pulsed collector current	160		A
$V_{GE}$	Gate-emitter voltage	$\pm 20$		V
$P_{TOT}$	Total dissipation at $T_C = 25^\circ\text{C}$	283	62.5	W
$V_{ISO}$	Insulation withstand voltage (RMS) from all three leads to external heat sink ( $t = 1 \text{ s}; T_c = 25^\circ\text{C}$ )		3.5	kV
$T_{STG}$	Storage temperature range	- 55 to 150		°C
$T_J$	Operating junction temperature	- 55 to 175		°C

1. Pulse width limited by maximum junction temperature.

**Table 3. Thermal data**

Symbol	Parameter	Value		Unit
		TO-247 TO-3P	TO-3PF	
$R_{thJC}$	Thermal resistance junction-case	0.53	2.4	°C/W
$R_{thJA}$	Thermal resistance junction-ambient	50		°C/W

## 2 Electrical characteristics

$T_J = 25^\circ\text{C}$  unless otherwise specified.

Table 4. Static characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{(\text{BR})\text{CES}}$	Collector-emitter breakdown voltage ( $V_{GE} = 0$ )	$I_C = 2 \text{ mA}$	650			V
$V_{CE(\text{sat})}$	Collector-emitter saturation voltage	$V_{GE} = 15 \text{ V}, I_C = 40 \text{ A}$		1.6	2.0	V
		$V_{GE} = 15 \text{ V}, I_C = 40 \text{ A}$ $T_J = 125^\circ\text{C}$		1.7		
		$V_{GE} = 15 \text{ V}, I_C = 40 \text{ A}$ $T_J = 175^\circ\text{C}$		1.8		
$V_{GE(\text{th})}$	Gate threshold voltage	$V_{CE} = V_{GE}, I_C = 1 \text{ mA}$	5	6	7	V
$I_{CES}$	Collector cut-off current ( $V_{GE} = 0$ )	$V_{CE} = 650 \text{ V}$			25	$\mu\text{A}$
$I_{GES}$	Gate-emitter leakage current ( $V_{CE} = 0$ )	$V_{GE} = \pm 20 \text{ V}$			250	nA

Table 5. Dynamic characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$C_{ies}$	Input capacitance	$V_{CE} = 25 \text{ V}, f = 1 \text{ MHz},$ $V_{GE} = 0$	-	5412	-	pF
$C_{oes}$	Output capacitance		-	198	-	pF
$C_{res}$	Reverse transfer capacitance		-	107	-	pF
$Q_g$	Total gate charge	$V_{CC} = 520 \text{ V}, I_C = 40 \text{ A},$ $V_{GE} = 15 \text{ V}$ , see <a href="#">Figure 28</a>	-	210	-	nC
$Q_{ge}$	Gate-emitter charge		-	39	-	nC
$Q_{gc}$	Gate-collector charge		-	82	-	nC

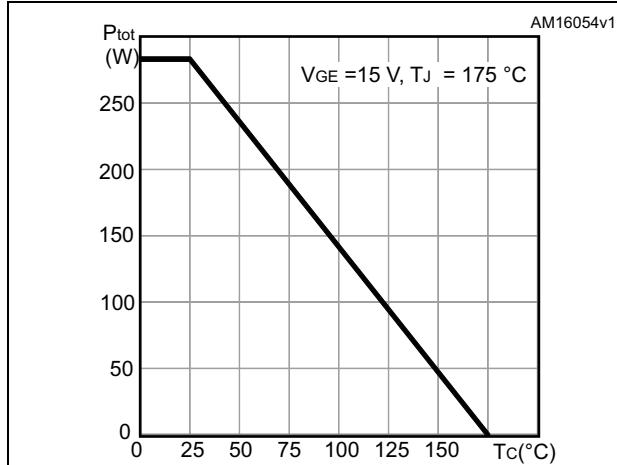
**Table 6. Switching characteristics (inductive load)**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$t_{d(on)}$	Turn-on delay time	$V_{CE} = 400 \text{ V}, I_C = 40 \text{ A}, R_G = 5 \Omega, V_{GE} = 15 \text{ V},$ see <a href="#">Figure 27</a>	-	40	-	ns
$t_r$	Current rise time		-	13	-	ns
$(di/dt)_{on}$	Turn-on current slope		-	2413	-	A/ $\mu\text{s}$
$t_{d(off)}$	Turn-off delay time		-	142	-	ns
$t_f$	Current fall time		-	27	-	ns
$E_{on}^{(1)}$	Turn-on switching losses		-	498	-	$\mu\text{J}$
$E_{off}^{(2)}$	Turn-off switching losses		-	363	-	$\mu\text{J}$
$E_{ts}$	Total switching losses		-	861	-	$\mu\text{J}$
$t_{d(on)}$	Turn-on delay time	$V_{CE} = 400 \text{ V}, I_C = 40 \text{ A}, R_G = 5 \Omega, V_{GE} = 15 \text{ V}, T_J = 175 \text{ }^\circ\text{C}$ , see <a href="#">Figure 27</a>	-	38	-	ns
$t_r$	Current rise time		-	14	-	ns
$(di/dt)_{on}$	Turn-on current slope		-	2186	-	A/ $\mu\text{s}$
$t_{d(off)}$	Turn-off delay time		-	141	-	ns
$t_f$	Current fall time		-	61	-	ns
$E_{on}^{(1)}$	Turn-on switching losses		-	1417	-	$\mu\text{J}$
$E_{off}^{(2)}$	Turn-off switching losses		-	764	-	$\mu\text{J}$
$E_{ts}$	Total switching losses		-	2181	-	$\mu\text{J}$

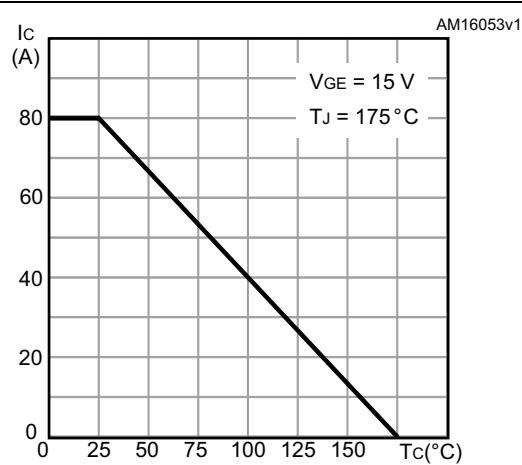
1. Energy losses include reverse recovery of the external diode. The diode is the same of the co-packed STGW40H65DFB.
2. Turn-off losses include also the tail of the collector current.

## 2.1 Electrical characteristics (curves)

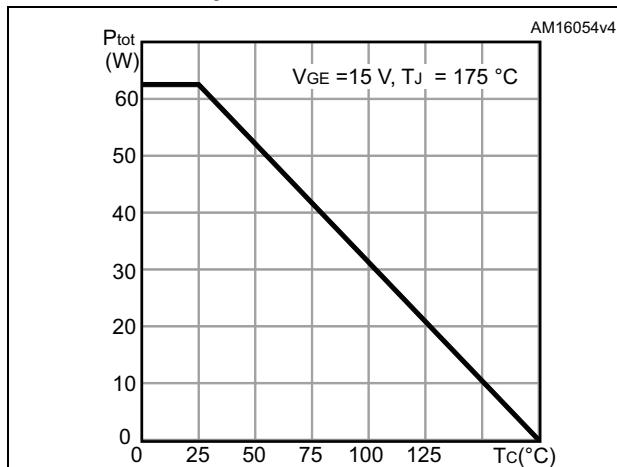
**Figure 2. Power dissipation vs. case temperature for TO-247 and TO-3P**



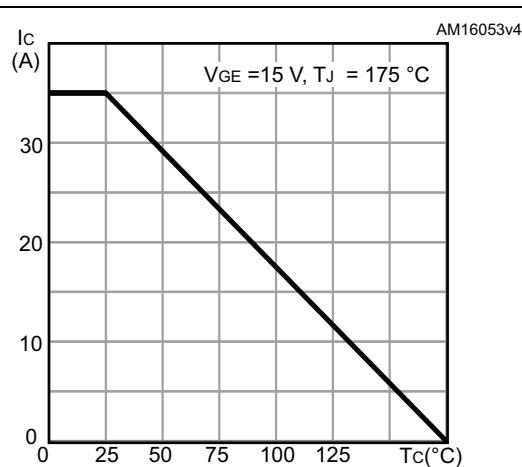
**Figure 3. Collector current vs. case temperature for TO-247 and TO-3P**



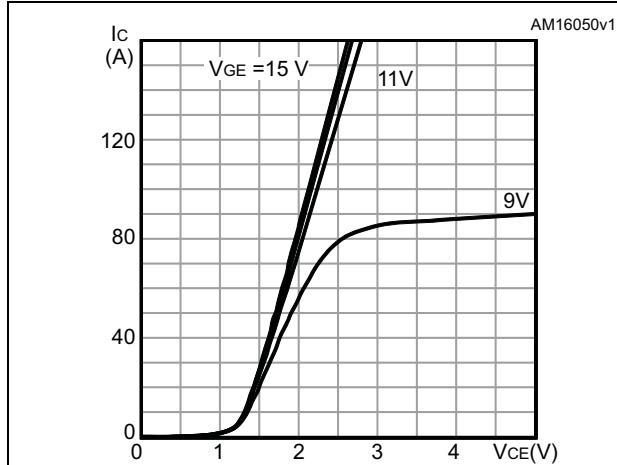
**Figure 4. Power dissipation vs. case temperature for TO-3PF**



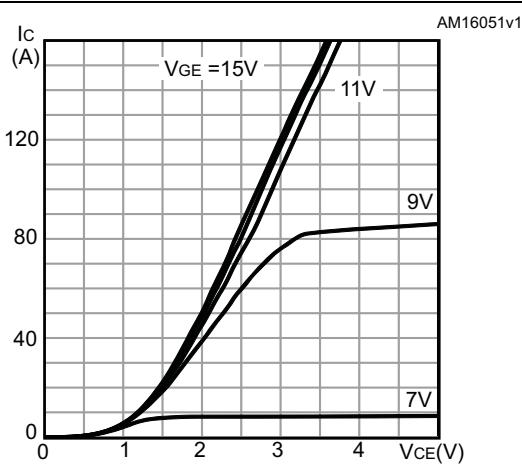
**Figure 5. Collector current vs. case temperature for TO-3PF**

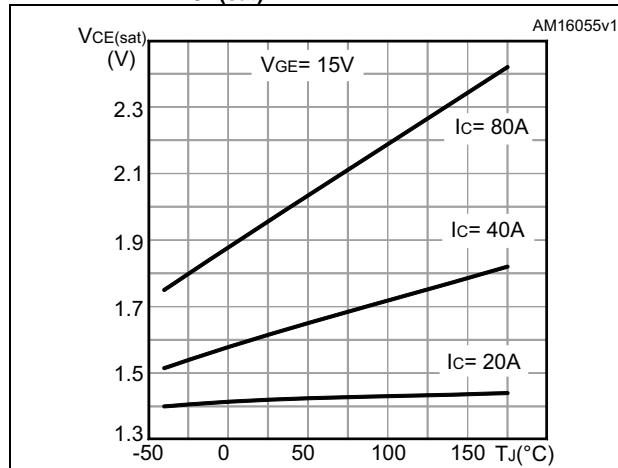
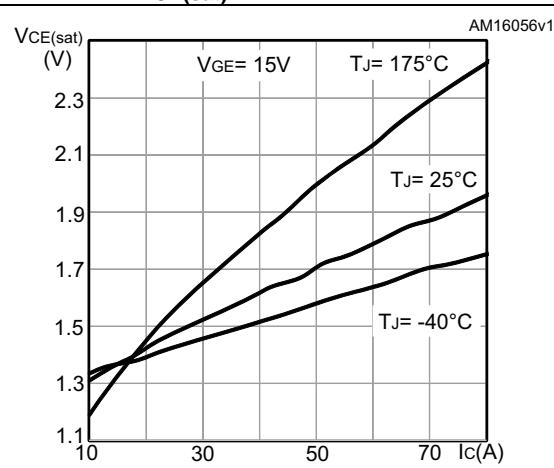
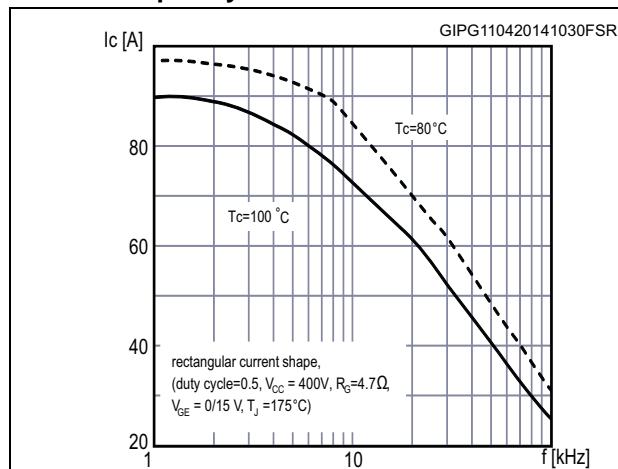
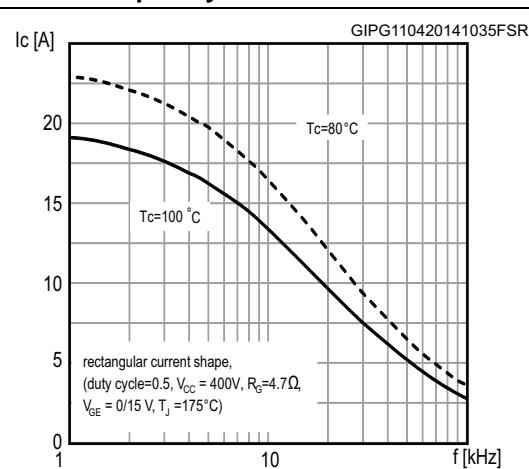
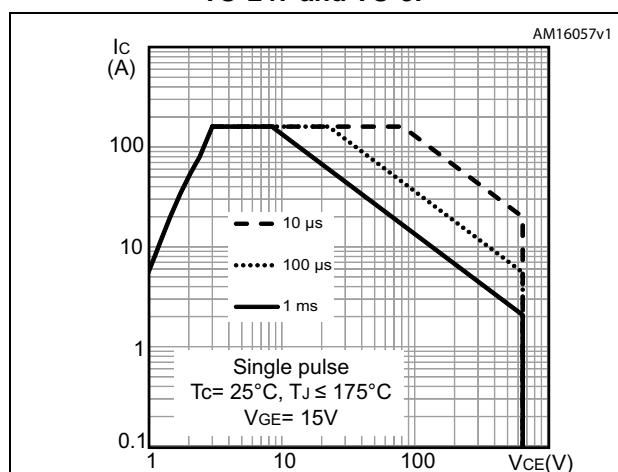
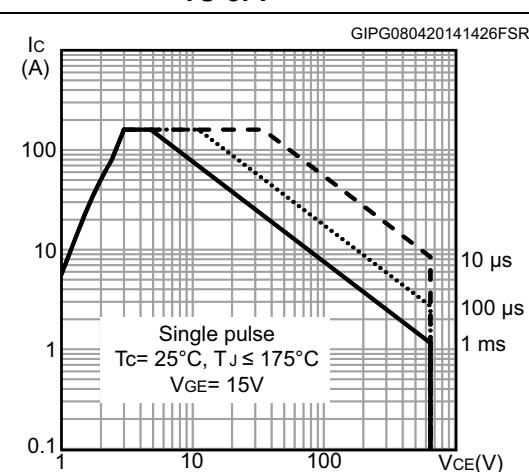


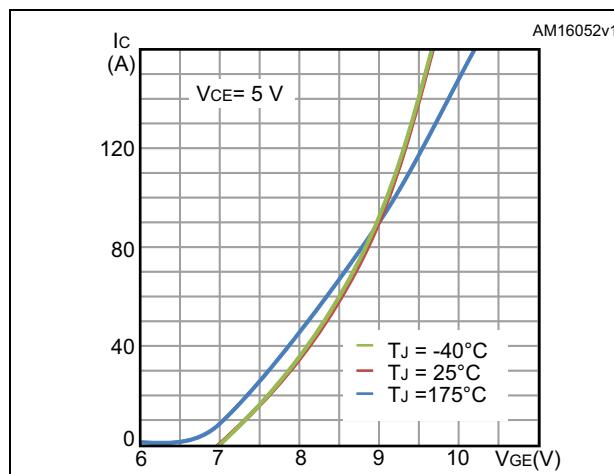
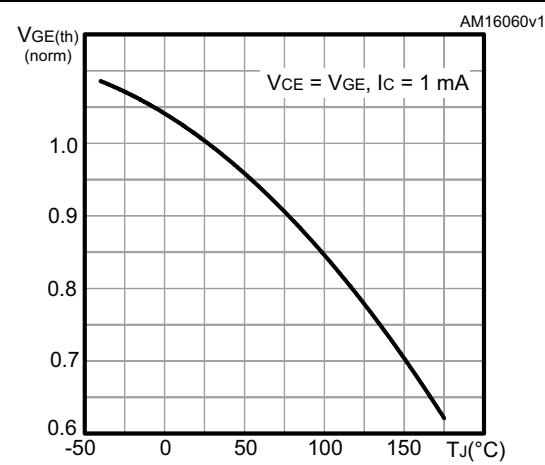
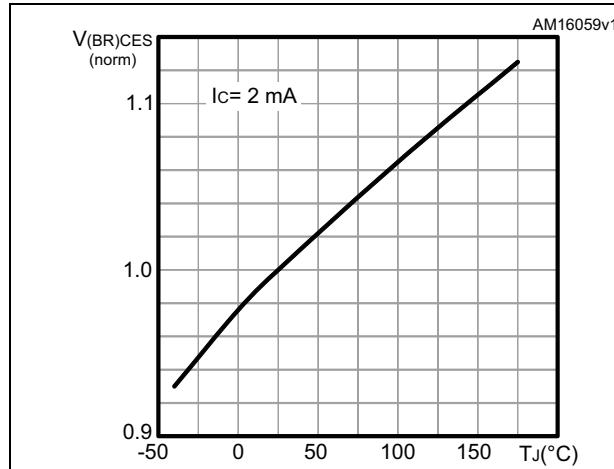
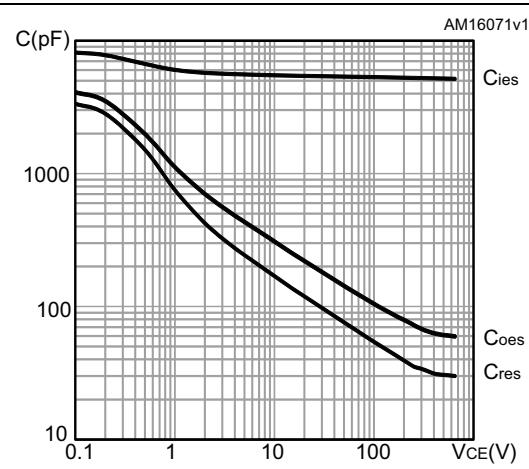
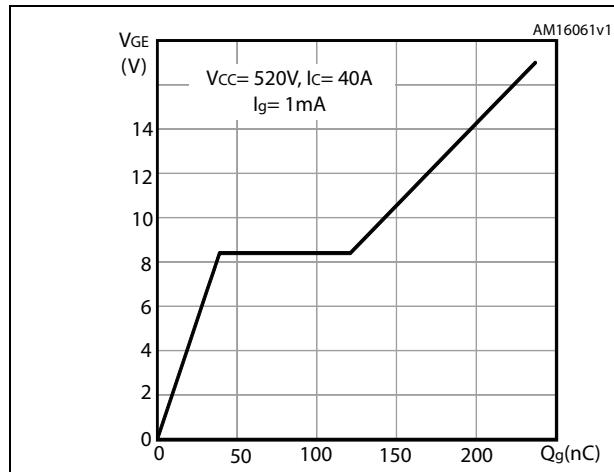
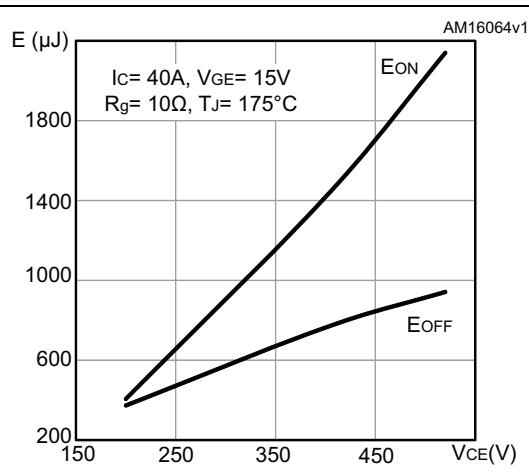
**Figure 6. Output characteristics ( $T_J = 25^{\circ}\text{C}$ )**



**Figure 7. Output characteristics ( $T_J = 175^{\circ}\text{C}$ )**



**Figure 8.  $V_{CE(sat)}$  vs. junction temperature****Figure 9.  $V_{CE(sat)}$  vs. collector current****Figure 10. Collector current vs. switching frequency for TO-247 and TO-3P****Figure 11. Collector current vs. switching frequency for TO-3PF****Figure 12. Forward bias safe operating area for TO-247 and TO-3P****Figure 13. Forward bias safe operating area for TO-3PF**

**Figure 14. Transfer characteristics****Figure 15. Normalized  $V_{GE(\text{th})}$  vs junction temperature****Figure 16. Normalized  $V_{(BR)CES}$  vs. junction temperature****Figure 17. Capacitance variation****Figure 18. Gate charge vs. gate-emitter voltage****Figure 19. Switching loss vs collector current**

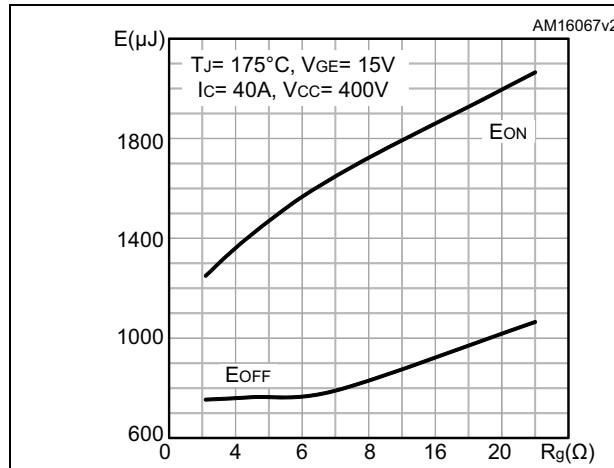
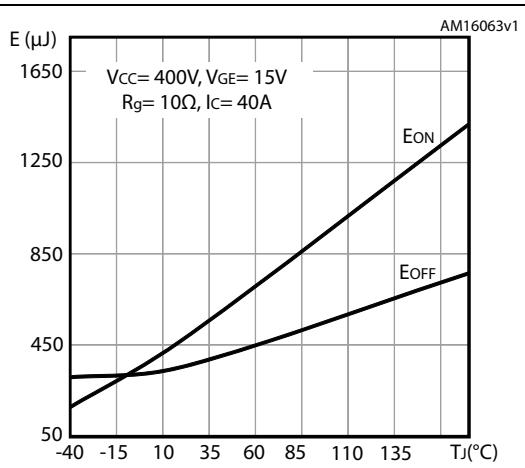
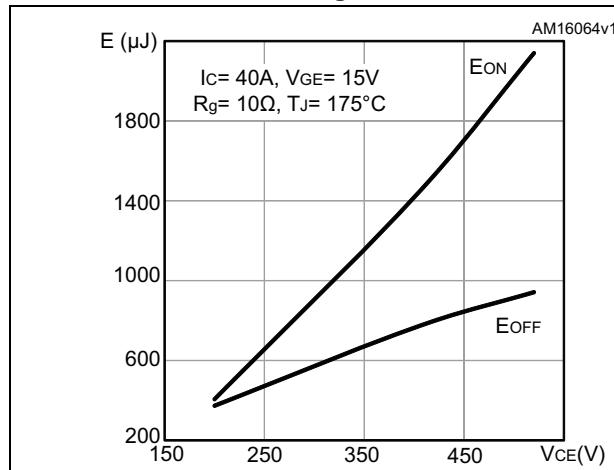
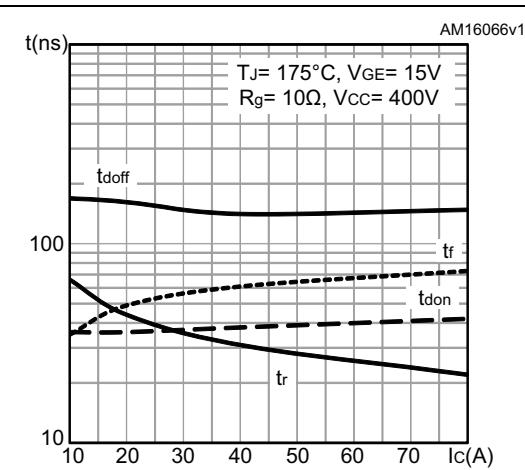
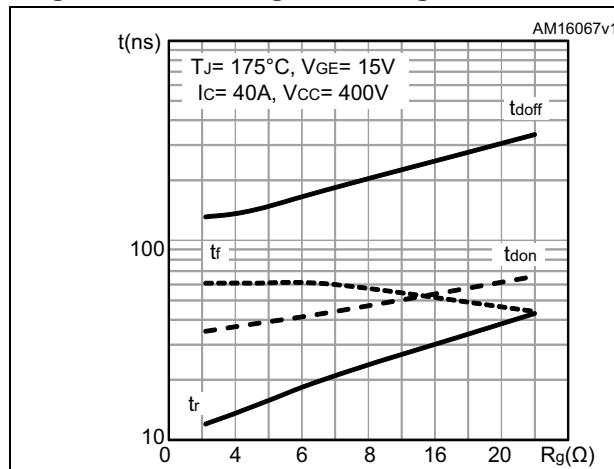
**Figure 20. Switching loss vs gate resistance****Figure 21. Switching loss vs temperature****Figure 22. Switching loss vs collector-emitter voltage****Figure 23. Switching times vs. collector current****Figure 24. Switching times vs. gate resistance**

Figure 25. Thermal impedance for TO-247 and TO-3P

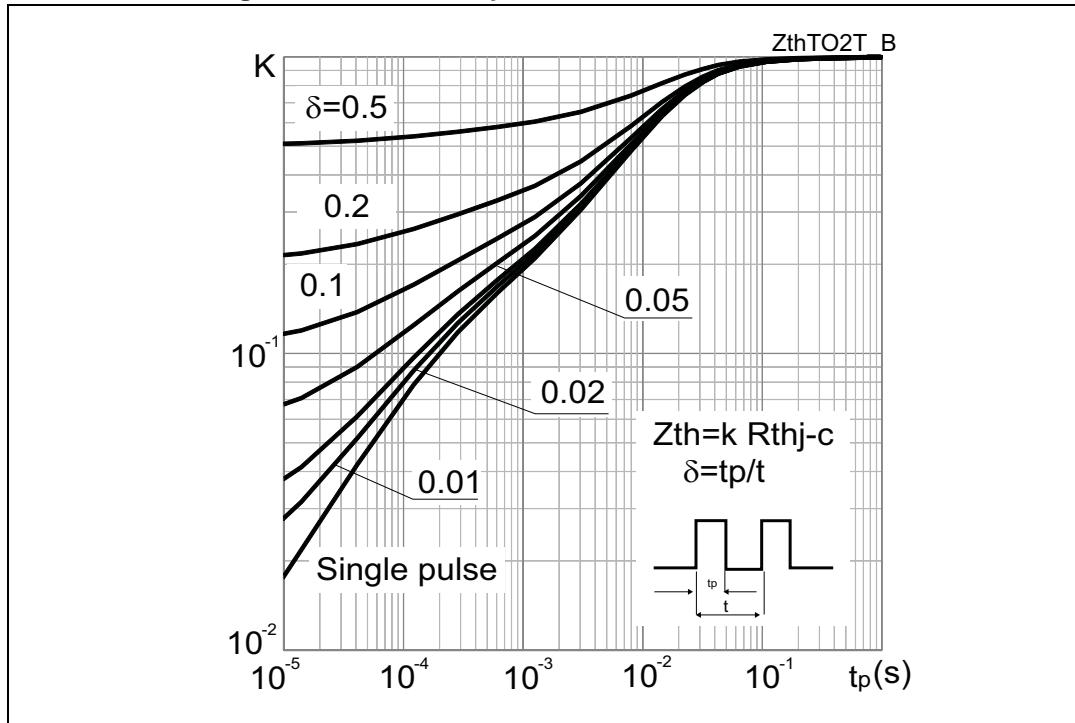
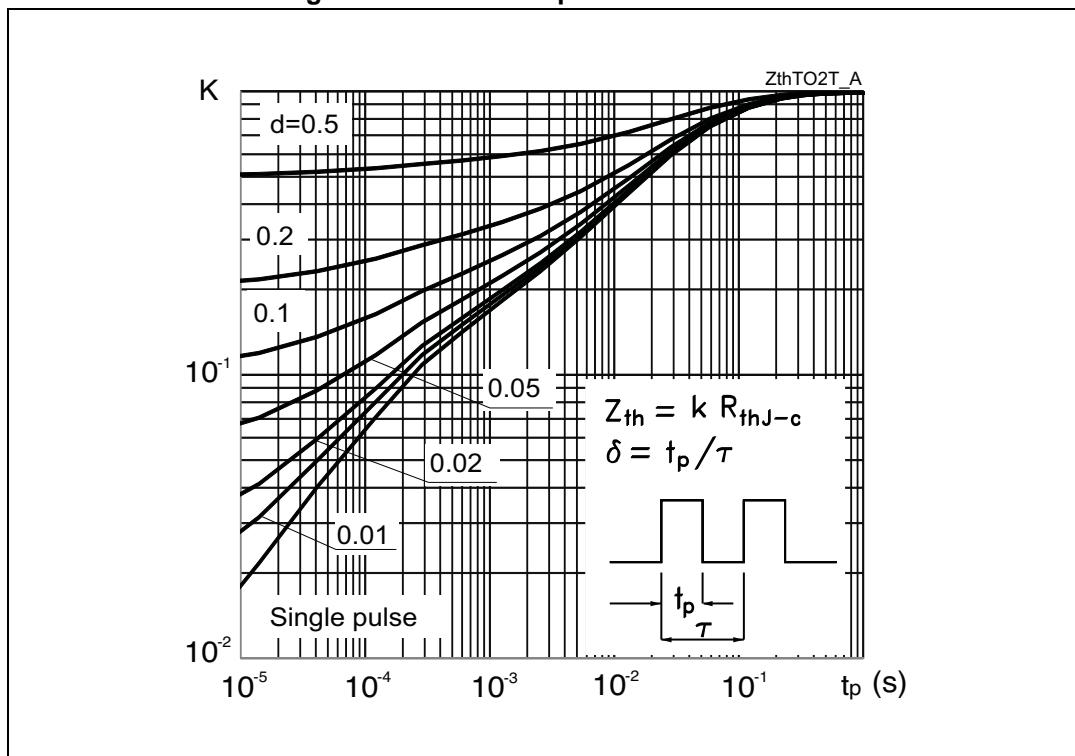
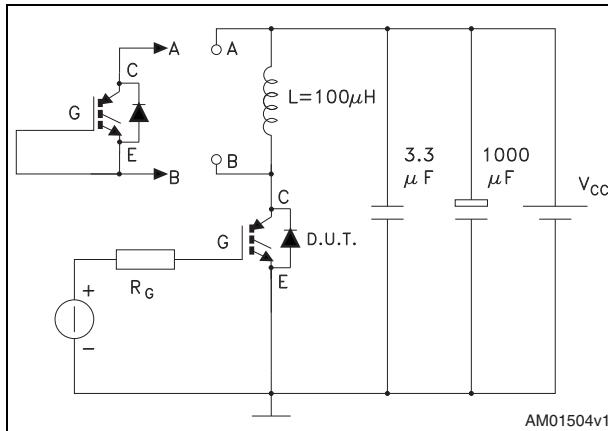


Figure 26. Thermal impedance for TO-3PF

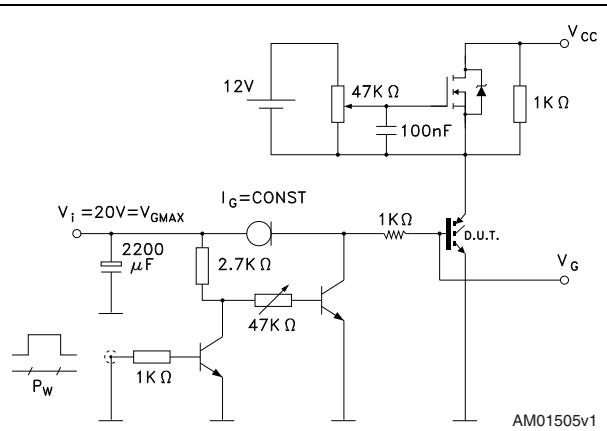


### 3 Test circuits

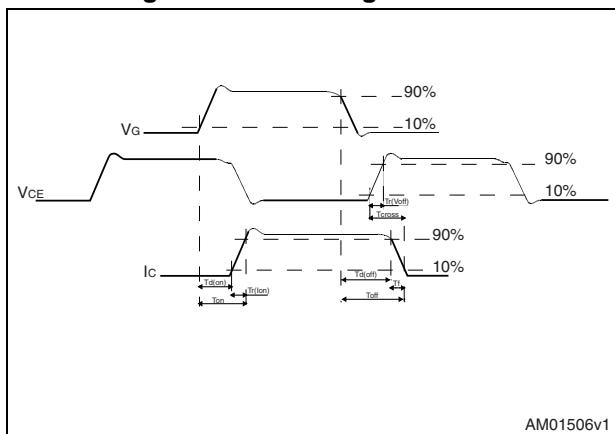
**Figure 27. Test circuit for inductive load switching**



**Figure 28. Gate charge test circuit**



**Figure 29. Switching waveform**

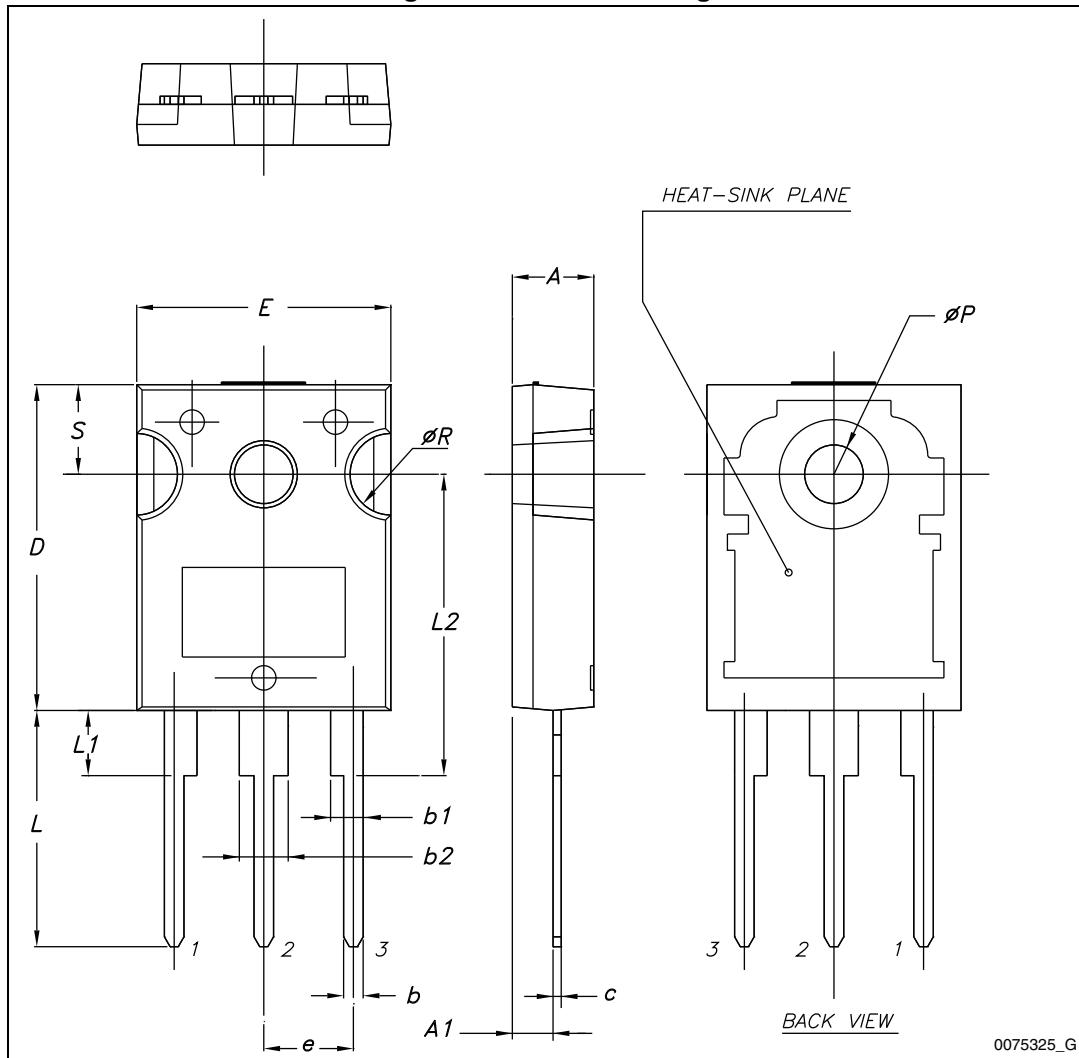


## 4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com).  
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### 4.1 TO-247, STGW40H65FB

Figure 30. TO-247 drawing

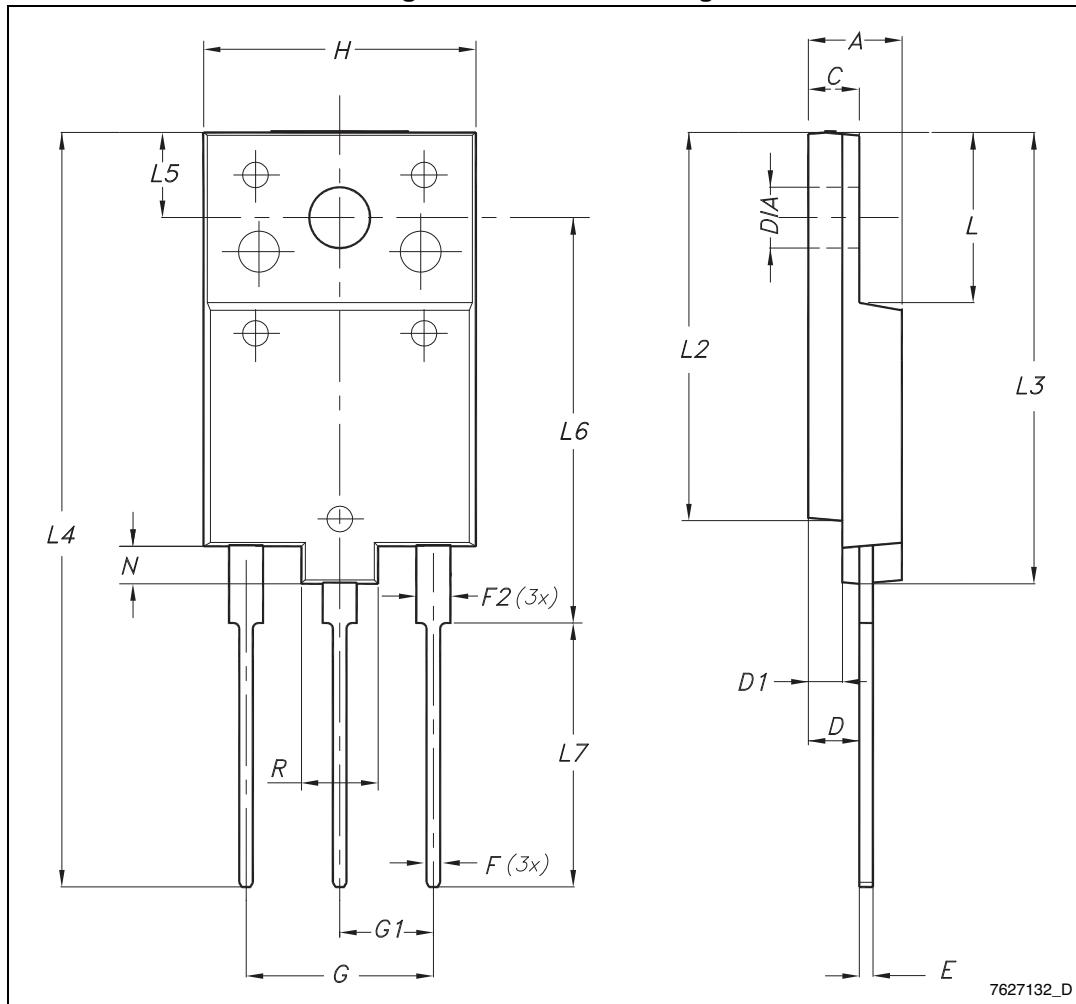


**Table 7. TO-247 mechanical data**

Dim.	mm.		
	Min.	Typ.	Max.
A	4.85		5.15
A1	2.20		2.60
b	1.0		1.40
b1	2.0		2.40
b2	3.0		3.40
c	0.40		0.80
D	19.85		20.15
E	15.45		15.75
e	5.30	5.45	5.60
L	14.20		14.80
L1	3.70		4.30
L2		18.50	
ØP	3.55		3.65
ØR	4.50		5.50
S	5.30	5.50	5.70

## 4.2 TO-3PF, STGFW40H65FB

Figure 31. TO-3PF drawing

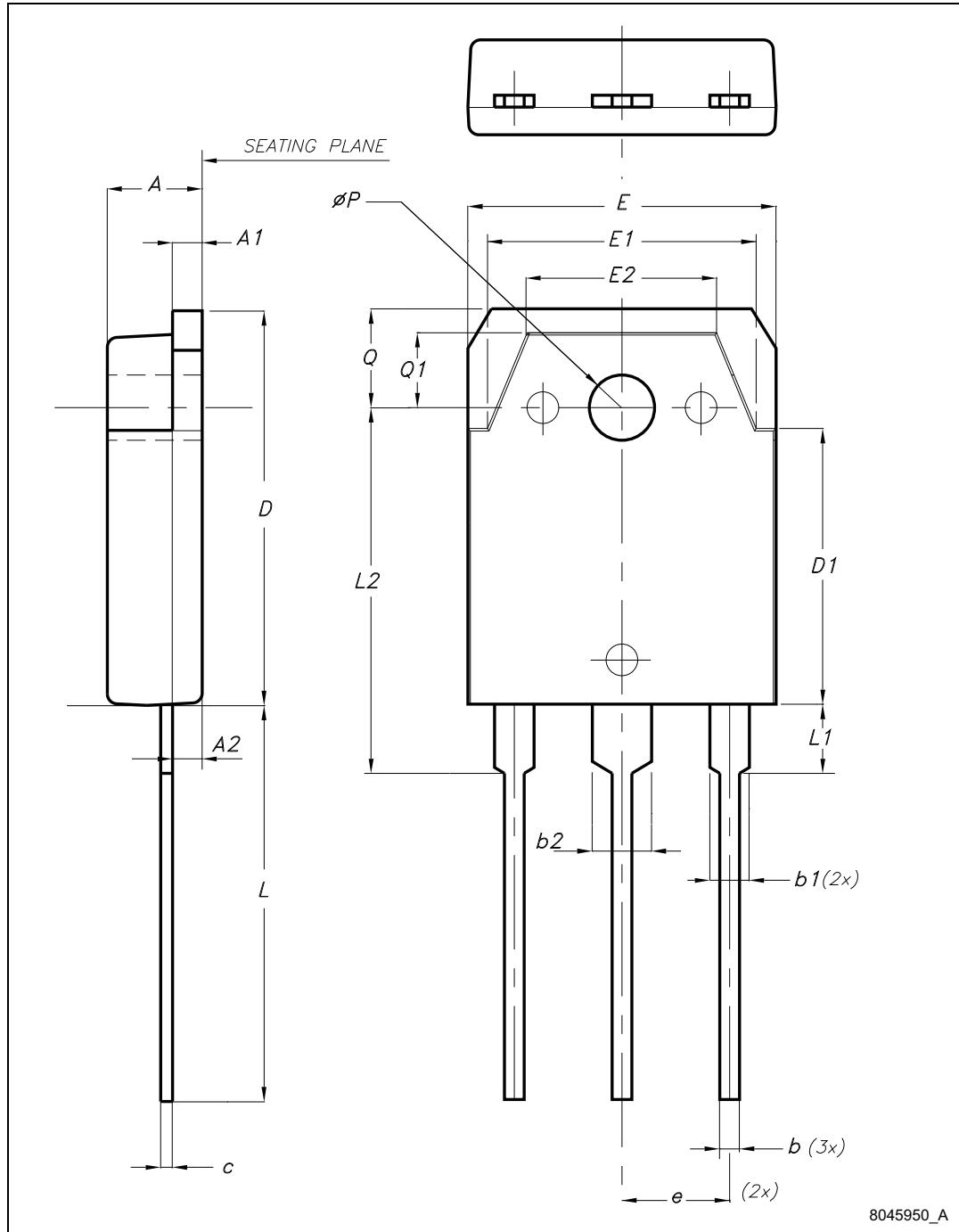


**Table 8. TO-3PF mechanical data**

Dim.	mm		
	Min.	Typ.	Max.
A	5.30		5.70
C	2.80		3.20
D	3.10		3.50
D1	1.80		2.20
E	0.80		1.10
F	0.65		0.95
F2	1.80		2.20
G	10.30		11.50
G1		5.45	
H	15.30		15.70
L	9.80	10	10.20
L2	22.80		23.20
L3	26.30		26.70
L4	43.20		44.40
L5	4.30		4.70
L6	24.30		24.70
L7	14.60		15
N	1.80		2.20
R	3.80		4.20
Dia	3.40		3.80

### 4.3 TO-3P, STGWT40H65FB

Figure 32. TO-3P drawing



**Table 9. TO-3P mechanical data**

Dim.	mm		
	Min.	Typ.	Max.
A	4.60		5
A1	1.45	1.50	1.65
A2	1.20	1.40	1.60
b	0.80	1	1.20
b1	1.80		2.20
b2	2.80		3.20
c	0.55	0.60	0.75
D	19.70	19.90	20.10
D1		13.90	
E	15.40		15.80
E1		13.60	
E2		9.60	
e	5.15	5.45	5.75
L	19.50	20	20.50
L1		3.50	
L2	18.20	18.40	18.60
øP	3.10		3.30
Q		5	
Q1		3.80	

## 5 Revision history

Document  
**Table 10. Document revision history**

Date	Revision	Changes
30-Aug-2013	1	Initial release.
11-Sep-2013	2	Document status changed from preliminary to production data. Inserted <a href="#">Section 2.1: Electrical characteristics (curves)</a> .
28-Feb-2014	3	Updated title and description in cover page.
05-Mar-2014	4	Updated units in <a href="#">Table 6: Switching characteristics (inductive load)</a> .
11-Apr-2014	5	Added part number and references for the device in a TO-3PF package

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